## NSN 5961-01-356-8462

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-356-8462 **Inclosure Material:** Plastic **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.125 inches and 0.165 inches **Overall Width:** Between 0.175 inches and 0.205 inches **Function For Which Designed:** Voltage variable capacitor **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 20.0 reverse voltage, dc **Current Rating Per Characteristic:** 400.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** Between 297.0 and 363.0 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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